

## CLAIMS:

- and*  
*a6* 5
1. An electro-optical device having an ITO (indium tin oxide) layer and a SiN layer near the ITO layer, characterized in that an intermediate layer of silicon oxide is provided between the ITO layer and the SiN layer.
  2. An electro-optical device as claimed in claim 1, characterized in that the electro-optical device is a fingerprint sensor.
  3. An electro-optical device as claimed in claim 1, characterized in that the electro-optical device is an X-ray image sensor.
- Add A7*